

74LVC157

Quad 2-Input Multiplexer

GENERAL DESCRIPTION

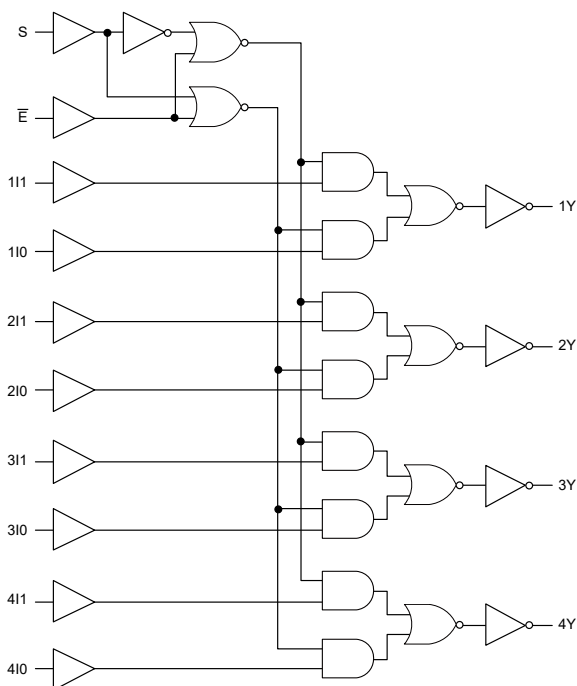
The 74LVC157 is a quad 2-input multiplexer designed for 1.2V to 3.6V operating voltage. The enable input (\bar{E}) is active low. When pin \bar{E} is high, all of the outputs (1Y to 4Y) are forced low regardless of all the other input conditions. When pin \bar{E} is low, four bits of data are selected from one of two sources that are determined by the state of the common data selection input (S), and are routed to the four outputs. The S input can also be used as function generator. The four outputs present the true (non-inverting) selected data.

It is useful for implementing highly irregular logic by generating any 4 of the 16 different functions of two variables with one variable common.

The device is the logic implementation of a 4-pole, 2-position switch, where the position of the switch is determined by the logic levels applied to pin S.

Inputs can be driven from either 3.3V or 5V devices. This feature allows the use of the device as a translator in mixed 3.3V and 5V applications.

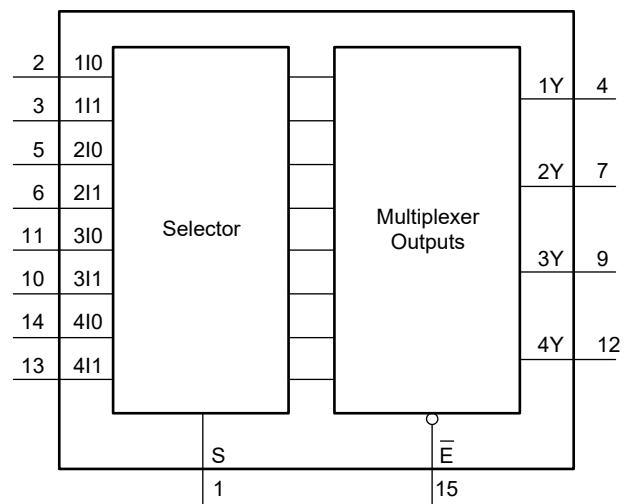
LOGIC SYMBOL



FEATURES

- 5V Tolerant Inputs for Interfacing with 5V Logic
- Wide Supply Voltage Range: 1.2V to 3.6V
- CMOS Low Power Consumption
- Direct Interface with TTL Levels
- -40°C to +125°C Operating Temperature Range
- Available in a Green TQFN-2.5×3.5-16L Package

LOGIC DIAGRAM



FUNCTION TABLE

CONTROL INPUT		INPUT		OUTPUT
\bar{E}	S	nI0	nI1	nY
H	X	X	X	L
L	L	L	X	L
L	L	H	X	H
L	H	X	L	L
L	H	X	H	H

H = High Voltage Level

L = Low Voltage Level

X = Don't Care

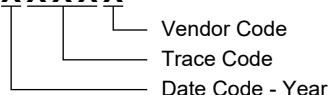
PACKAGE/ORDERING INFORMATION

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION
74LVC157	TQFN-2.5×3.5-16L	-40°C to +125°C	74LVC157XTRG16G/TR	R5ARG XXXXX	Tape and Reel, 6000

MARKING INFORMATION

NOTE: XXXXX = Date Code, Trace Code and Vendor Code.

XXXXX



Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

ABSOLUTE MAXIMUM RATINGS ⁽¹⁾

Supply Voltage, V_{CC}	-0.5V to 6.5V
Input Voltage, V_I ⁽²⁾	-0.5V to 6.5V
Output Voltage, V_O ⁽²⁾	-0.5V to $V_{CC} + 0.5V$
Input Clamping Current, I_{IK} ($V_I < 0V$).....	-50mA
Output Clamping Current, I_{OK} ($V_O > V_{CC}$ or $V_O < 0V$).....	±50mA
Output Current, I_O ($V_O = 0V$ to V_{CC}).....	±50mA
Supply Current, I_{CC}	100mA
Ground Current, I_{GND}	-100mA
Junction Temperature ⁽³⁾	+150°C
Storage Temperature Range.....	-65°C to +150°C
Lead Temperature (Soldering, 10s).....	+260°C
ESD Susceptibility	
HBM.....	6000V
CDM.....	1000V

RECOMMENDED OPERATING CONDITIONS

Supply Voltage, V_{CC}	1.65V to 3.6V
Data Retention Only, V_{CC}	1.2V to 3.6V
Input Voltage, V_I	0V to 5.5V
Output Voltage, V_O	0V to V_{CC}
Input Transition Rise and Fall Rate, $\Delta t/\Delta V$	
$V_{CC} = 1.65V$ to $2.7V$	20ns/V (MAX)
$V_{CC} = 2.7V$ to $3.6V$	10ns/V (MAX)
Operating Temperature Range.....	-40°C to +125°C

OVERSTRESS CAUTION

1. Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.
2. The input and output voltage ratings may be exceeded if the input and output clamp current ratings are observed.
3. The performance capability of a high-performance integrated circuit in conjunction with its thermal environment can create junction temperatures which are detrimental to reliability.

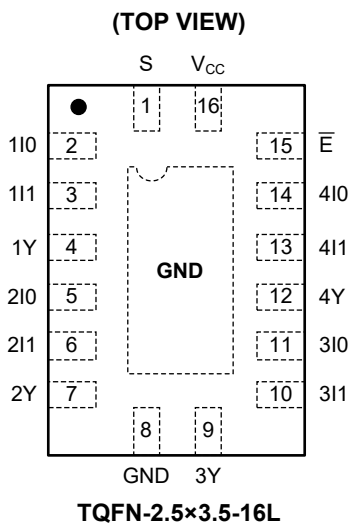
ESD SENSITIVITY CAUTION

This integrated circuit can be damaged if ESD protections are not considered carefully. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because even small parametric changes could cause the device not to meet the published specifications.

DISCLAIMER

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.

PIN CONFIGURATION



PIN DESCRIPTION

PIN	NAME	FUNCTION
1	S	Common Data Selection Input.
2, 5, 11, 14	1I0, 2I0, 3I0, 4I0	Source 0 Data Inputs.
3, 6, 10, 13	1I1, 2I1, 3I1, 4I1	Source 1 Data Inputs.
4, 7, 9, 12	1Y, 2Y, 3Y, 4Y	Multiplexer Outputs.
8	GND	Ground.
15	E-bar	Enable Input (Active Low).
16	VCC	Supply Voltage.
Exposed Pad	GND	This is not a supply pin. The exposed pad can be left floating or soldered to the ground.

ELECTRICAL CHARACTERISTICS(Full = -40°C to +125°C, all typical values are measured at $V_{CC} = 3.3V$ and $T_A = +25^\circ C$, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	TEMP	MIN	TYP	MAX	UNITS
High-Level Input Voltage	V_{IH}	$V_{CC} = 1.2V$	Full	1.05			V
		$V_{CC} = 1.65V$ to $1.95V$	Full	$0.65 \times V_{CC}$			
		$V_{CC} = 2.3V$ to $2.7V$	Full	1.5			
		$V_{CC} = 2.7V$ to $3.6V$	Full	1.8			
Low-Level Input Voltage	V_{IL}	$V_{CC} = 1.2V$	Full			0.4	V
		$V_{CC} = 1.65V$ to $1.95V$	Full			$0.35 \times V_{CC}$	
		$V_{CC} = 2.3V$ to $2.7V$	Full			0.7	
		$V_{CC} = 2.7V$ to $3.6V$	Full			0.8	
High-Level Output Voltage	V_{OH}	$V_I = V_{IH}$ or V_{IL}	$V_{CC} = 1.65V$ to $3.6V$, $I_O = -100\mu A$	Full	$V_{CC} - 0.05$	$V_{CC} - 0.005$	V
			$V_{CC} = 1.65V$, $I_O = -4mA$	Full	1.45	1.55	
			$V_{CC} = 2.3V$, $I_O = -8mA$	Full	2.05	2.15	
			$V_{CC} = 2.7V$, $I_O = -12mA$	Full	2.4	2.55	
			$V_{CC} = 3.0V$, $I_O = -18mA$	Full	2.55	2.75	
			$V_{CC} = 3.0V$, $I_O = -24mA$	Full	2.45	2.7	
Low-Level Output Voltage	V_{OL}	$V_I = V_{IH}$ or V_{IL}	$V_{CC} = 1.65V$ to $3.6V$, $I_O = 100\mu A$	Full		0.005	V
			$V_{CC} = 1.65V$, $I_O = 4mA$	Full		0.1	
			$V_{CC} = 2.3V$, $I_O = 8mA$	Full		0.15	
			$V_{CC} = 2.7V$, $I_O = 12mA$	Full		0.15	
			$V_{CC} = 3.0V$, $I_O = 24mA$	Full		0.3	
Input Leakage Current	I_I	$V_{CC} = 3.6V$, $V_I = 5.5V$ or GND	Full		± 0.05	± 10	μA
Supply Current	I_{CC}	$V_{CC} = 3.6V$, $V_I = V_{CC}$ or GND, $I_O = 0A$	Full		0.05	10	μA
Additional Supply Current	ΔI_{CC}	Per input pin, $V_{CC} = 2.7V$ to $3.6V$, $V_I = V_{CC} - 0.6V$, $I_O = 0A$	Full		0.05	20	μA
Input Capacitance	C_I	$V_{CC} = 0V$ to $3.6V$, $V_I = GND$ to V_{CC}	+25°C		7		pF

DYNAMIC CHARACTERISTICS

(For test circuit, see Figure 1. Full = -40°C to +125°C, all typical values are measured at $T_A = +25^\circ\text{C}$ and $V_{CC} = 1.2\text{V}, 1.8\text{V}, 2.5\text{V}, 2.7\text{V}$ and 3.3V respectively, unless otherwise noted.)

PARAMETER	SYMBOL	CONDITIONS	TEMP	MIN ⁽¹⁾	TYP	MAX ⁽¹⁾	UNITS
Propagation Delay ⁽²⁾	t_{PD}	nI0, nI1 to nY, see Figure 2	$V_{CC} = 1.2\text{V}$	+25°C	15.0		ns
			$V_{CC} = 1.65\text{V to } 1.95\text{V}$	Full	0.5	7.0	
			$V_{CC} = 2.3\text{V to } 2.7\text{V}$	Full	0.5	4.0	
			$V_{CC} = 2.7\text{V}$	Full	0.5	4.0	
			$V_{CC} = 3.0\text{V to } 3.6\text{V}$	Full	0.5	4.0	
		\bar{E} to nY, see Figure 3	$V_{CC} = 1.2\text{V}$	+25°C	12.0		ns
			$V_{CC} = 1.65\text{V to } 1.95\text{V}$	Full	0.5	6.0	
			$V_{CC} = 2.3\text{V to } 2.7\text{V}$	Full	0.5	4.0	
			$V_{CC} = 2.7\text{V}$	Full	0.5	4.0	
			$V_{CC} = 3.0\text{V to } 3.6\text{V}$	Full	0.5	4.0	
		S to nY, see Figure 2	$V_{CC} = 1.2\text{V}$	+25°C	14.0		ns
			$V_{CC} = 1.65\text{V to } 1.95\text{V}$	Full	0.5	8.0	
			$V_{CC} = 2.3\text{V to } 2.7\text{V}$	Full	0.5	4.0	
			$V_{CC} = 2.7\text{V}$	Full	0.5	4.0	
			$V_{CC} = 3.0\text{V to } 3.6\text{V}$	Full	0.5	4.0	
Output Skew Time	$t_{SK(O)}$	$V_{CC} = 3.0\text{V to } 3.6\text{V}$		Full	0.5	1.5	ns
Power Dissipation Capacitance ⁽³⁾	C_{PD}	Per input, $V_I = \text{GND to } V_{CC}$	$V_{CC} = 1.65\text{V to } 1.95\text{V}$	+25°C	15		pF
			$V_{CC} = 2.3\text{V to } 2.7\text{V}$	+25°C	16		
			$V_{CC} = 3.0\text{V to } 3.6\text{V}$	+25°C	17		

NOTES:

- Specified by design and characterization; not production tested.
- t_{PD} is the same as t_{PLH} and t_{PHL} .
- C_{PD} is used to determine the dynamic power dissipation (P_D in μW).

$$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$$

where:

f_i = Input frequency in MHz.

f_o = Output frequency in MHz.

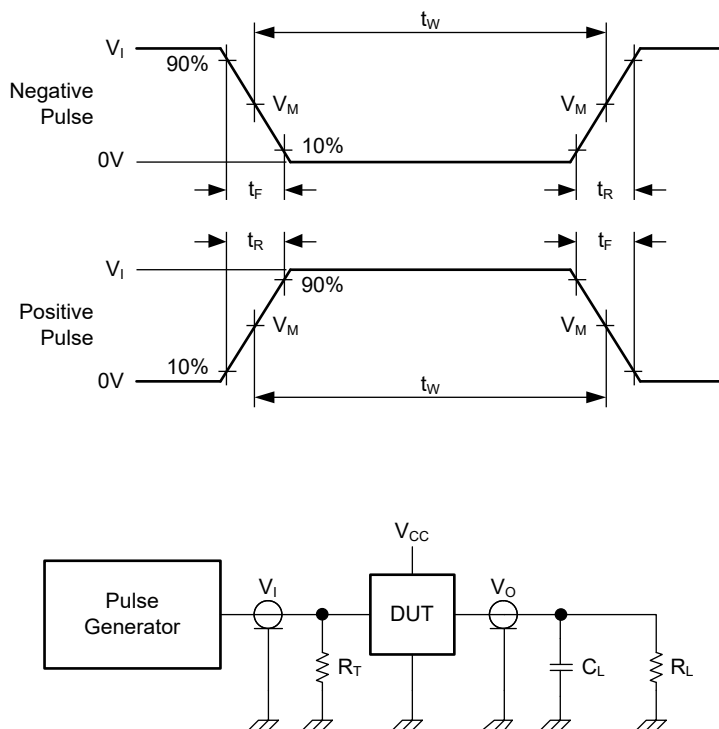
C_L = Output load capacitance in pF.

V_{CC} = Supply voltage in Volts.

N = Number of inputs switching.

$\Sigma(C_L \times V_{CC}^2 \times f_o)$ = Sum of outputs.

TEST CIRCUIT



Test conditions are given in Table 1.

Definitions for test circuit:

R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

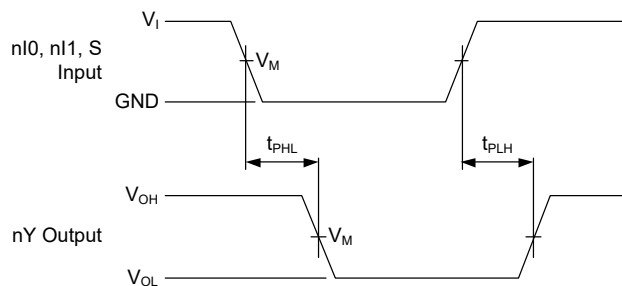
R_T = Termination resistance should be equal to output impedance Z_O of the pulse generator.

Figure 1. Test Circuit for Measuring Switching Times

Table 1. Test Conditions

SUPPLY VOLTAGE	INPUT		LOAD	
V_{CC}	V_I	t_R, t_F	C_L	R_L
1.2V	V_{CC}	$\leq 2\text{ns}$	30pF	1k Ω
1.65V to 1.95V	V_{CC}	$\leq 2\text{ns}$	30pF	1k Ω
2.3V to 2.7V	V_{CC}	$\leq 2\text{ns}$	30pF	500 Ω
2.7V	2.7V	$\leq 2.5\text{ns}$	50pF	500 Ω
3.0V to 3.6V	2.7V	$\leq 2.5\text{ns}$	50pF	500 Ω

WAVEFORMS

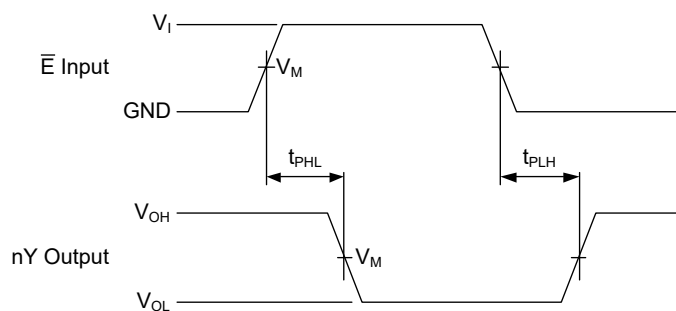


Test conditions are given in Table 1.

Measurement points are given in Table 2.

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Figure 2. Data Inputs (nI0, nI1) and Common Data Selection Input (S) to Output (nY) Propagation Delays



Test conditions are given in Table 1.

Measurement points are given in Table 2.

Logic levels: V_{OL} and V_{OH} are typical output voltage levels that occur with the output load.

Figure 3. Enable Input (\bar{E}) to Output (nY) Propagation Delays

Table 2. Measurement Points

SUPPLY VOLTAGE	INPUT		OUTPUT
V_{CC}	V_I	$V_M^{(1)}$	V_M
1.2V	V_{CC}	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$
1.65V to 1.95V	V_{CC}	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$
2.3V to 2.7V	V_{CC}	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$
2.7V	2.7V	1.5V	1.5V
3.0V to 3.6V	2.7V	1.5V	1.5V

NOTE:

1. The measurement points should be V_{IH} or V_{IL} when the input rising or falling time exceeds 2.5ns.

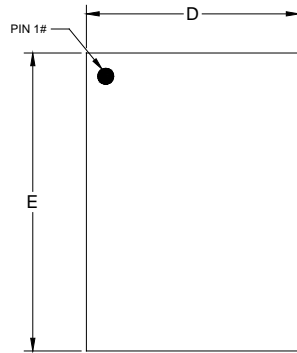
REVISION HISTORY

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

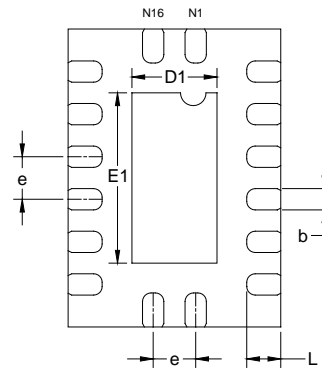
OCTOBER 2021 – REV.A to REV.A.1	Page
Updated Dynamic Characteristics section.....	5
Added Table 2 and note in Waveforms section.....	7
Changes from Original (FEBRUARY 2021) to REV.A	Page
Changed from product preview to production data.....	All

PACKAGE OUTLINE DIMENSIONS

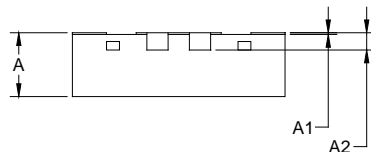
TQFN-2.5×3.5-16L



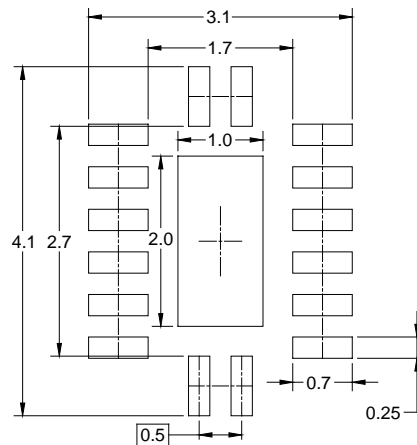
TOP VIEW



BOTTOM VIEW



SIDE VIEW



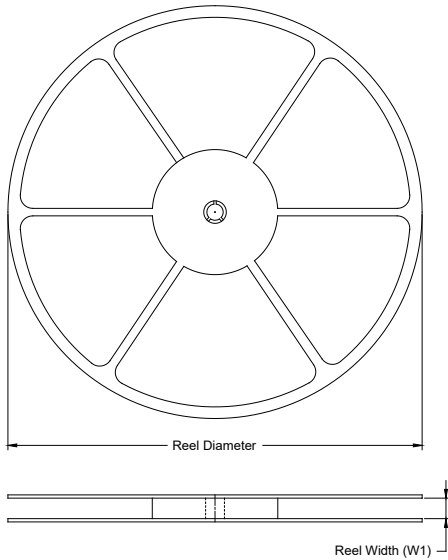
RECOMMENDED LAND PATTERN (Unit: mm)

Symbol	Dimensions In Millimeters		
	MIN	MOD	MAX
A	0.70	0.75	0.80
A1	0.00	0.02	0.05
A2	0.203 REF		
b	0.20	0.25	0.30
D	2.40	2.50	2.60
D1	0.85	1.00	1.15
E	3.40	3.50	3.60
E1	1.85	2.00	2.15
e	0.45	0.50	0.55
L	0.30	0.40	0.50

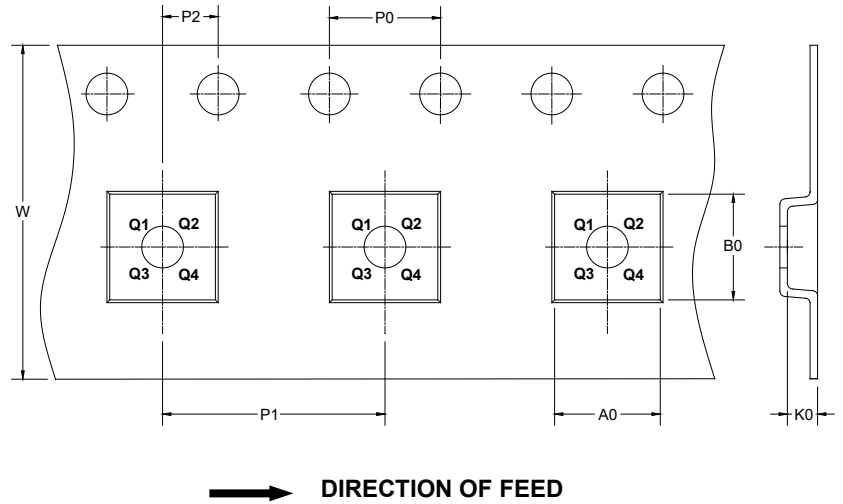
PACKAGE INFORMATION

TAPE AND REEL INFORMATION

REEL DIMENSIONS



TAPE DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

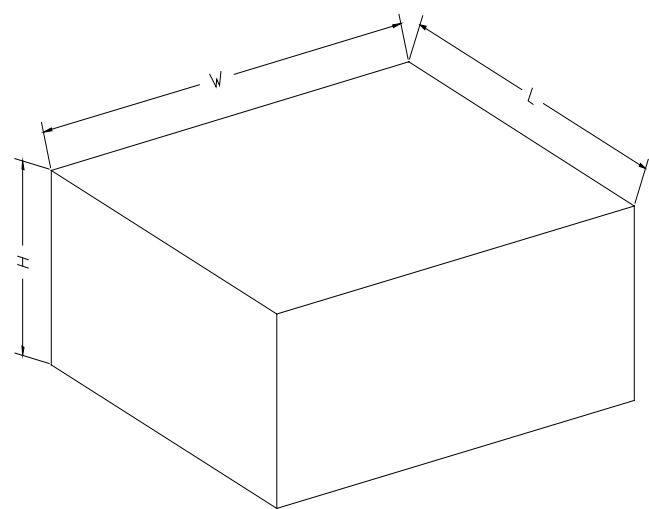
KEY PARAMETER LIST OF TAPE AND REEL

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
TQFN-2.5×3.5-16L	13"	12.4	2.80	3.80	0.95	4.0	8.0	2.0	12.0	Q1

DD00001

PACKAGE INFORMATION

CARTON BOX DIMENSIONS



NOTE: The picture is only for reference. Please make the object as the standard.

KEY PARAMETER LIST OF CARTON BOX

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton
13"	386	280	370	5

DD0002